

QUICKSWITCH[®] PRODUCTS 2.5V / 3.3V 10-BIT FLOW-THROUGH PIN OUT, HIGH BANDWIDTH SWITCH

IDTQS3VH2861

FEATURES:

- N channel FET switches with no parasitic diode to Vcc
- Isolation under power-off conditions
- No DC path to Vcc or GND
- 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- · Flat Row characteristics over operating range
- Rail-to-rail switching 0 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent Row matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth
- LVTTL-compatible control Inputs
- · Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- 25Ω resistors for low noise and line matching
- Available in QSOP package

APPLICATIONS:

- Hot-swapping
- Low distortion analog switch
- · Replaces mechanical relay
- ATM 25/155 switching

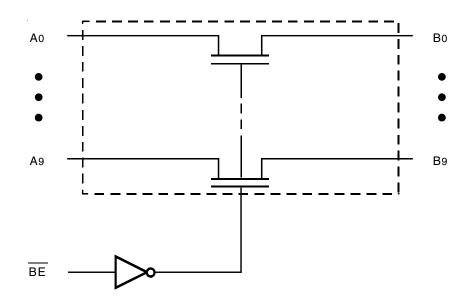
DESCRIPTION:

The QS3VH2861 HotSwitch is a high bandwidth bus switch with 10-bit flow-though pin out. The QS3VH2861, with 25Ω ON resistance and 1.35ns propagation delay, is ideal for line matching and low noise environments. The switches are controlled by active low enable ($\overline{\text{BE}}$) control. In the ON state, the switches can pass signals up to 5V. In the OFF state, the switches offer very high impedence at the terminals.

The combination of small propagation delay, high OFF impedance, and over-voltage tolerance makes the QS3VH2861 ideal for high performance communications applications.

The QS3VH2861 is characterized for operation from -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM



The IDT logo is a registered trademark of Integrated Device Technology, Inc.

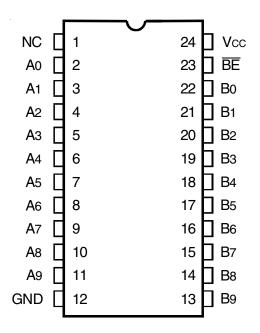
FEBRUARY 2014

IDTQS3VH2861

2.5V/3.3V10-BITACTIVE HIGH AND LOW ENABLE, HIGH BANDWIDTH SWITCH

INDUSTRIAL TEMPERATURE RANGE

PIN CONFIGURATION



QSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	SupplyVoltage to Ground	-0.5 to +4.6	V
VTERM ⁽³⁾	DC Switch Voltage Vs	-0.5 to +5.5	V
VTERM ⁽³⁾	DC Input Voltage VIN	-0.5 to +5.5	V
VAC	AC Input Voltage (pulse width ≤20ns)	ዻ	V
Ιουτ	DC Output Current (max. sink current/pin)	120	mA
Tstg	Storage Temperature	–65 to +150	°C

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc .

CAPACITANCE (TA = +25°C, F = 1MHz, VIN = 0V, VOUT = 0V)

Symbol	Parameter ⁽¹⁾	Тур.	Max.	Unit
CIN	Control Inputs	3	5	рF
CI/O	Quickswitch Channels (Switch OFF)	4	6	рF
Cı/o	Quickswitch Channels (Switch ON)	8	12	pF

NOTE:

1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	Description
BE	Active LOW Bus Enable
A0 - A9	Bus A
B0 - B9	Bus B

FUNCTION TABLE(1)

BE	A0 - A9	Function
Н	Z	Disconnect
L	B0 - B9	Connect

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

Z = High-Impedence

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

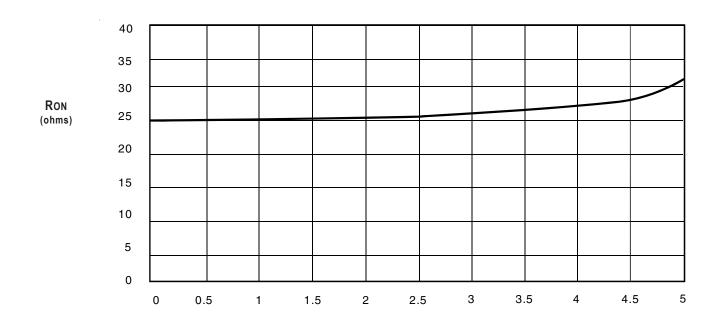
Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40°C to +85°C, Vcc = $3.3V \pm 0.3V$

Symbol	Parameter	Test 0	Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH	Vcc = 2.3V to 2.7	V	1.7	_	_	V
		for Control Inputs	Vcc = 2.7V to 3.6	νV	2	—	—	
VIL	Input LOW Voltage	Guaranteed Logic LOW	Vcc = 2.3V to 2.7	V	—	—	0.7	V
		for Control Inputs	Vcc = 2.7V to 3.6	ïV	_	_	0.8]
lin	Input Leakage Current (Control Inputs)	$0V \le VIN \le VCC$		_	—	±1	μA	
loz	Off-State Current (Hi-Z)	$0V \le VOUT \le 5V$, Switches OFF		_	_	±1	μA	
IOFF	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, Vcc =	VIN or VOUT 0V to 5V, VCC = 0V		—	—	±1	μA
		Vcc = 2.3V	VIN = 0V	Ion = 30mA	18	27	39	
Ron	Switch ON Resistance	Typical at Vcc = 2.5V	VIN = 1.7V	Ion = 15mA	18	28	41	Ω
		Vcc = 3V	VIN = 0V	Ion = 30mA	18	25	38]
			VIN = 2.4V	Ion = 15mA	18	26	40	1

NOTE:

1. Typical values are at Vcc = 3.3V and TA = 25° C.

TYPICAL ON RESISTANCE vs VIN AT Vcc = 3.3V



VIN (Volts)

INDUSTRIAL TEMPERATURE RANGE

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Min.	Тур.	Max.	Unit
lccq	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc, f = 0	—	2	4	mA
Δlcc	Power Supply Current ^(2,3) per Input HIGH	Vcc = Max., VIN = 3V, f = 0 per Control Input	—	_	30	μA
ICCD	Dynamic Power Supply Current (4)	Vcc = 3.3V, A and B Pins Open, Control Inputs	See Typical	ICCD vs Enabl	e Frequency	graph below
		Toggling @ 50% Duty Cycle				

NOTES:

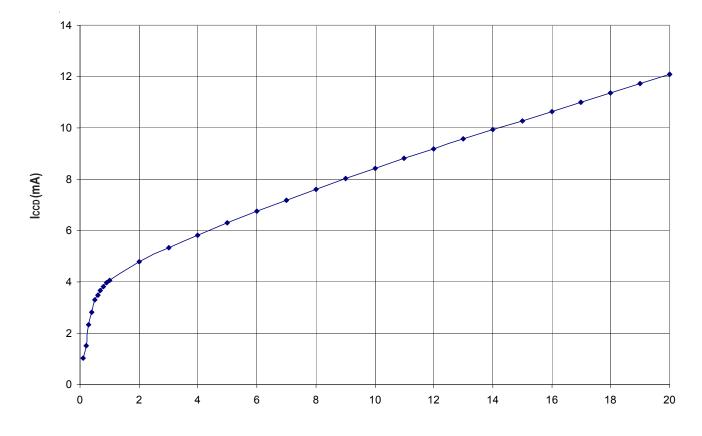
1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per input driven at the specified level. A and B pins do not contribute to Δ lcc.

3. This parameter is guaranteed but not tested.

4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

TYPICAL ICCD vs ENABLE FREQUENCY CURVE AT VCC = 3.3V



ENABLE FREQUENCY (MHz)

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

TA = -40°C to +85°C

		$Vcc = 2.5 \pm 0.2 V^{(1)}$		$Vcc = 3.3 \pm 0.3 V^{(1)}$		
Symbol	Parameter	Min. ⁽⁴⁾	Max.	Min. ⁽⁴⁾	Max.	Unit
tPLH	Data Propagation Delay ^(2,3)		0.9	—	1.35	ns
t PHL	Ax to Bx or Bx to Ax					
tPZH	Switch Turn-On Delay	1.5	9	1.5	8	ns
tPZL	BE to Ax or Bx					
tPHZ	Switch Turn-Off Delay	1.5	7.5	1.5	7.5	ns
tPLZ	BE to Ax or Bx					
ÍBE	Operating Frequency-Enable ^(2,5)		10		20	MHz

NOTES:

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.

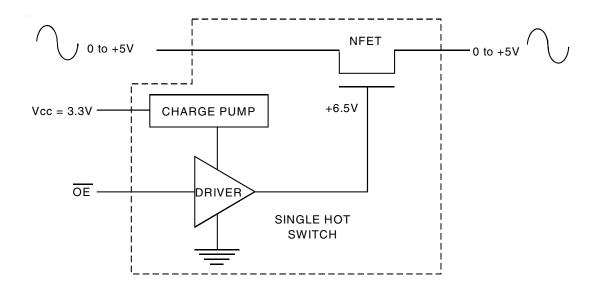
2. This parameter is guaranteed but not production tested.

3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 1.35ns at CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

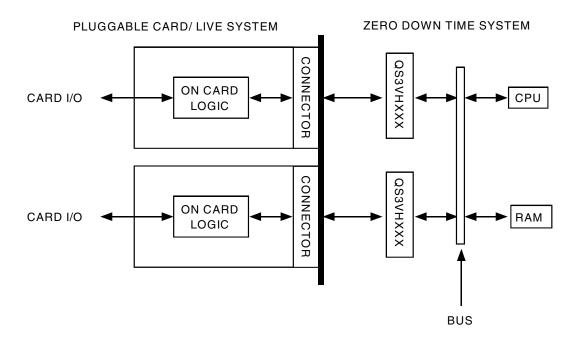
4. Minimums are guaranteed but not production tested.

5. Maximum toggle frequency for \overline{BE} control input (pass voltage > Vcc, VIN = 5V, RLOAD $\geq 1M\Omega$, no CLOAD).

SOME APPLICATIONS FOR HOTSWITCH PRODUCTS



Rail-to-Rail Switching

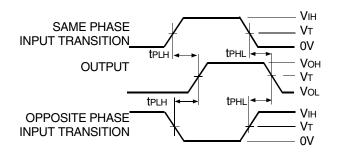


Hot-Swapping

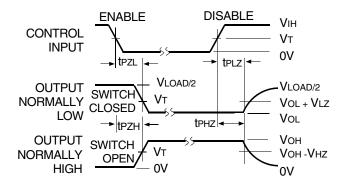
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$Vcc^{(1)}= 3.3V \pm 0.3V$	$Vcc^{(2)}= 2.5V \pm 0.2V$	Unit
Vload	6	2 x Vcc	V
Vih	3	Vcc	V
Vτ	1.5	Vcc/2	V
Vlz	300	150	mV
Vнz	300	150	mV
CL	50	30	pF



Propagation Delay

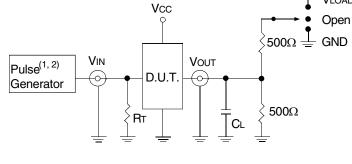


NOTE:

VLOAD

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

NOTES:

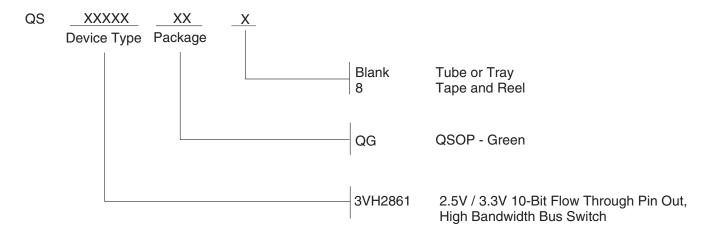
1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.

2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
tplz/tpzL	Vload
tрнz/tpzн	GND
tPD	Open

ORDERING INFORMATION



IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use o any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Disclaimer Rev.1.0 Mar 2020)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners. **Contact Information**

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit: <u>www.renesas.com/contact/</u>